

## LOW NOISE DUAL OPERATIONAL AMPLIFIER

- LOW VOLTAGE NOISE: **4.5nV/ $\sqrt{\text{Hz}}$**
- HIGH GAIN BANDWIDTH PRODUCT:  
**15MHz**
- HIGH SLEW RATE: **7V/ $\mu\text{s}$**
- LOW DISTORTION: 0.002%
- EXCELLENT FREQUENCY STABILITY
- ESD PROTECTION 2kV

**DESCRIPTION**

The LM833 is a monolithic dual operational amplifier particularly well suited for audio applications. It offers low voltage noise ( $4.5\text{nV}/\sqrt{\text{Hz}}$ ) and high frequency performances (15MHz Gain Bandwidth product,  $7\text{V}/\mu\text{s}$  slew rate).

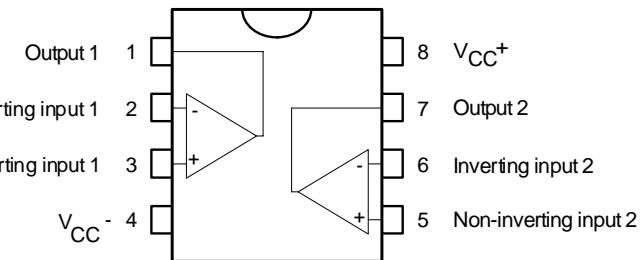
In addition the LM833 has also a very low distortion (0.002%) and excellent phase/gain margins.

**ORDER CODE**

Part Number	Temperature Range	Package	
		N	D
LM833	-40°C, +105°C	•	•

N = Dual in Line Package (DIP)

D = Small Outline Package (SO) - also available in Tape & Reel (DT)

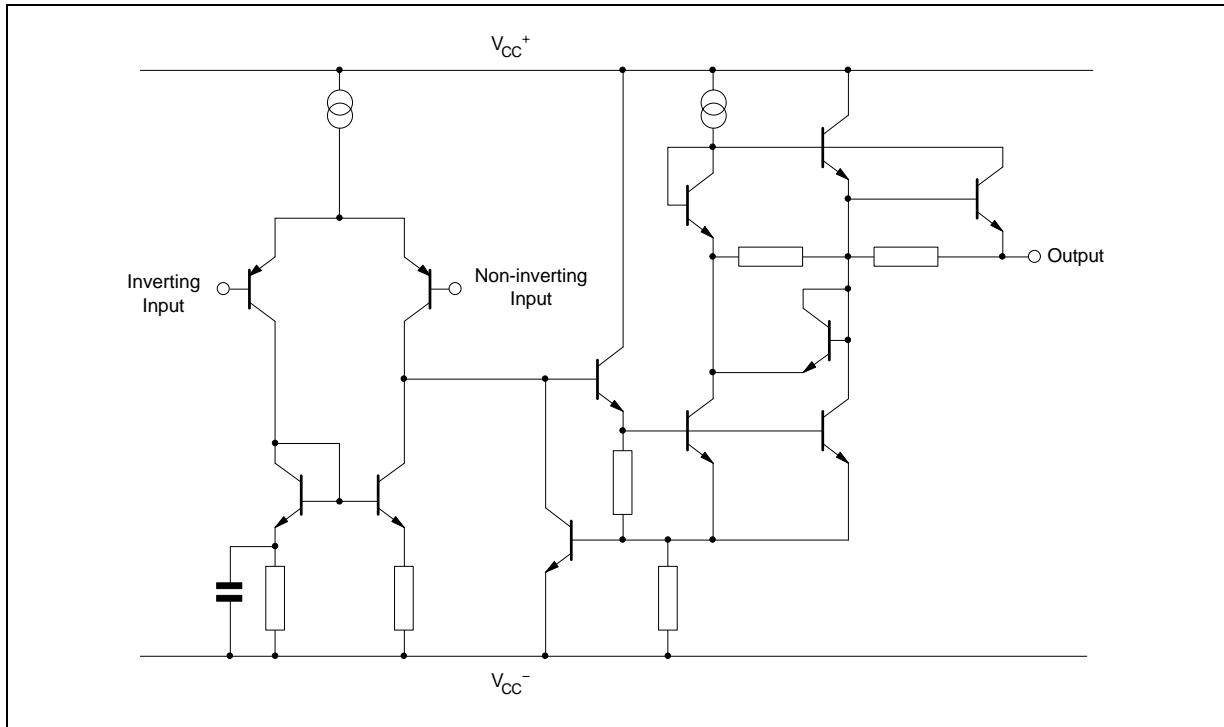
**PIN CONNECTIONS (top view)**

**N**  
**DIP8**  
(Plastic Package)



**D**  
**SO8**  
(Plastic Micropackage)

## SCHEMATIC DIAGRAM (1/2 LM833)



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	$\pm 18$ or $+36$	V
$V_{id}$	Differential Input Voltage - note 1)	$\pm 30$	V
$V_i$	Input Voltage - see note 1	$\pm 15$	V
	Output Short Circuit Duration	Infinite	s
$T_{oper}$	Operating Free-Air Temperature Range	-40 to 105	°C
$T_j$	Junction Temperature	+150	°C
$T_{stg}$	Storage Temperature	-65 to +150	°C
$P_{tot}$	Maximum Power Dissipation - note 2)	500	mW

1. Either or both input voltages must not exceed the magnitude of  $V_{CC}^+$  or  $V_{CC}^-$ .

2. Power dissipation must be considered to ensure maximum junction temperature ( $T_j$ ) is not exceeded.

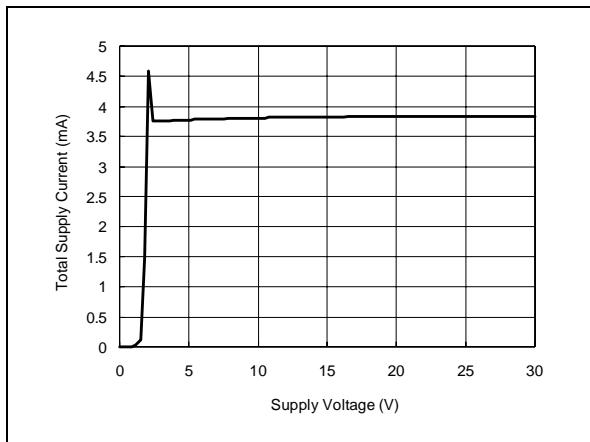
## OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	$\pm 2.5$ to $\pm 15$	V

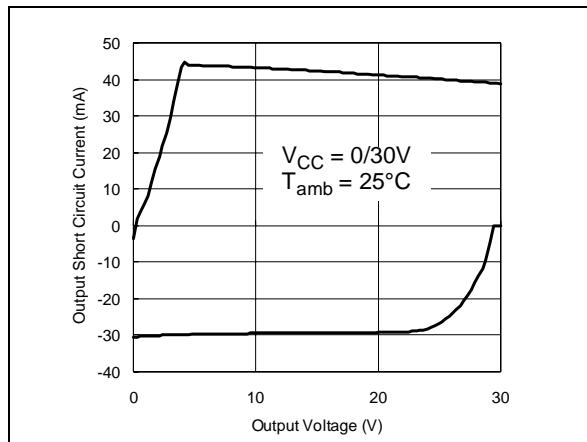
**ELECTRICAL CHARACTERISTICS** $V_{CC}^+ = +15V$ ,  $V_{CC}^- = -15V$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input Offset Voltage ( $R_s = 10\Omega$ , $V_o = 0V$ , $V_{ic} = 0V$ )		0.3	5	mV
$DV_{io}$	Input Offset Voltage Drift $R_s = 10\Omega$ , $V_o = 0V$ , $T_{min} \leq T_{amb} \leq T_{max}$ .		2		$\mu V/^\circ C$
$I_{io}$	Input Offset Current ( $V_o = 0V$ , $V_{ic} = 0V$ )		25	200	nA
$I_{ib}$	Input Bias Current ( $V_o = 0V$ , $V_{ic} = 0V$ )		300	1000	nA
$V_{icm}$	Input Common Mode Voltage Range	$\pm 12$	$\pm 14$		V
$A_{vd}$	Large Signal Voltage Gain ( $R_L = 2k\Omega$ , $V_o = \pm 10V$ )	90	100		dB
$\pm V_{opp}$	Output Voltage Swing ( $V_{id} = \pm 1V$ ) $R_L = 2.0k\Omega$ $R_L = 2.0k\Omega$ $R_L = 10k\Omega$ $R_L = 10k\Omega$	10	13.7		
		12	-14	-10	V
			13.9		
			-14.4	-12	
CMR	Common-mode Rejection Ratio ( $V_{ic} = \pm 13V$ )	80	100		dB
SVR	Supply Voltage Rejection Ratio ( $V_{CC}^+ / V_{CC}^- = +15V / -15V$ to $+5V / -5V$ )	80	105		dB
$I_{CC}$	Supply Current ( $V_o = 0V$ , All amplifiers)		4	8	mA
SR	Slew Rate ( $V_i = -10V$ to $+10V$ , $R_L = 2k\Omega$ , $A_V = +1$ )	5	7		V/ $\mu$ s
GBP	Gain Bandwidth Product ( $R_L = 2k\Omega$ , $C_L = 100pF$ , $f = 100kHz$ )	10	15		MHz
B	Unity Gain Bandwidth (Open loop)		9		MHz
$\phi_m$	Phase Margin ( $R_L = 2k\Omega$ )		60		Degrees
$e_n$	Equivalent Input Noise Voltage ( $R_S = 100\Omega$ , $f = 1kHz$ )		4.5		$\frac{nV}{\sqrt{Hz}}$
$i_n$	Equivalent Input Noise Current ( $f = 1kHz$ )		0.5		$\frac{pA}{\sqrt{Hz}}$
THD	Total Harmonic Distortion ( $R_L = 2k\Omega$ , $f = 20Hz$ to $20kHz$ , $V_o = 3V_{rms}$ , $A_V = +1$ )		0.002		%
$V_{O1}/V_{O2}$	Channel Separation ( $f = 20Hz$ to $20kHz$ )		120		dB
FPB	Full Power Bandwidth ( $V_o = 27V_{pp}$ , $R_L = 2k\Omega$ , THD $\leq 1\%$ )		120		kHz

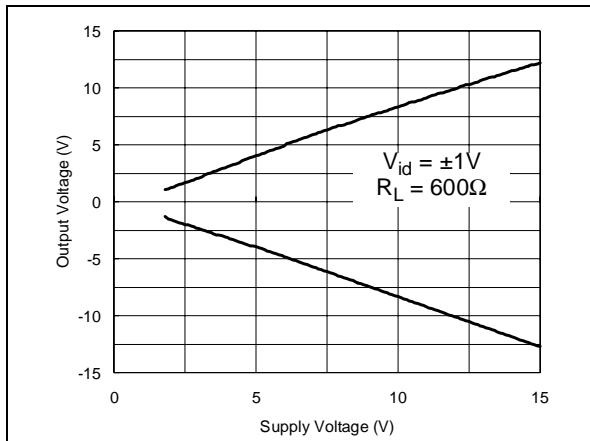
**TOTAL SUPPLY CURRENT vs SUPPLY VOLTAGE**



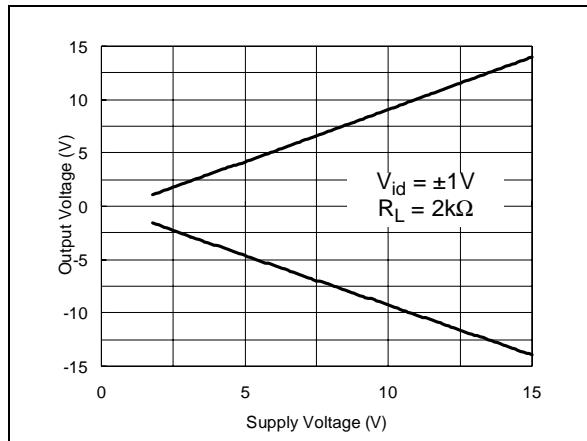
**OUTPUT SHORT CIRCUIT CURRENT vs OUTPUT VOLTAGE**



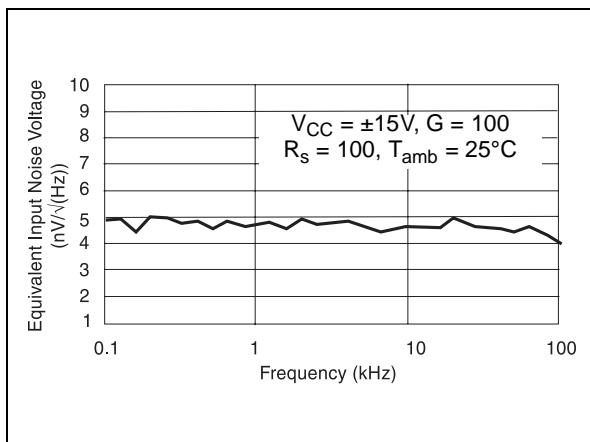
**OUTPUT VOLTAGE vs SUPPLY VOLTAGE**



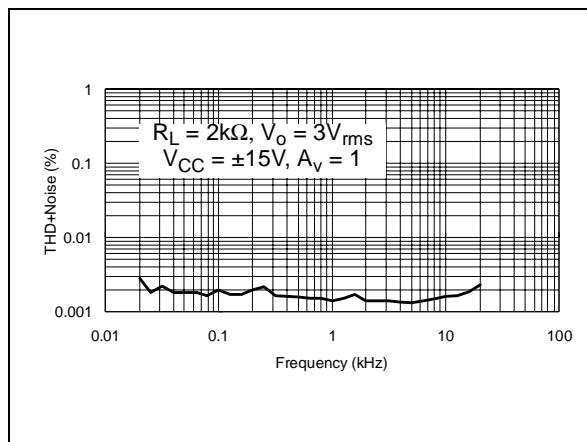
**OUTPUT VOLTAGE vs SUPPLY VOLTAGE**

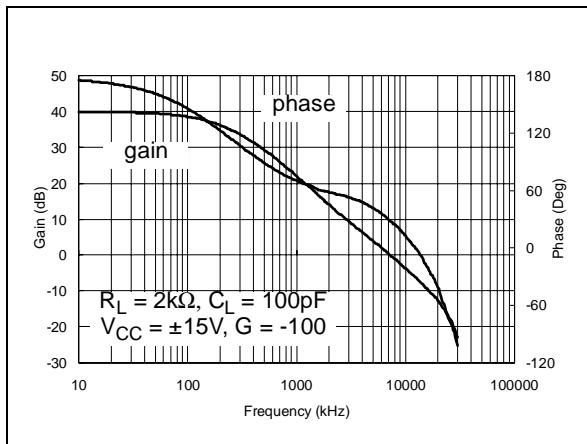
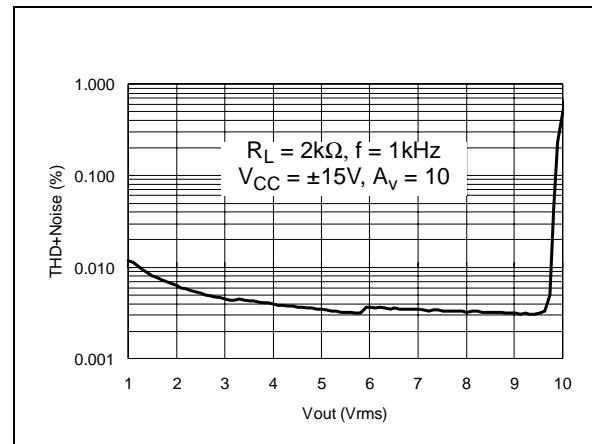


**EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY**

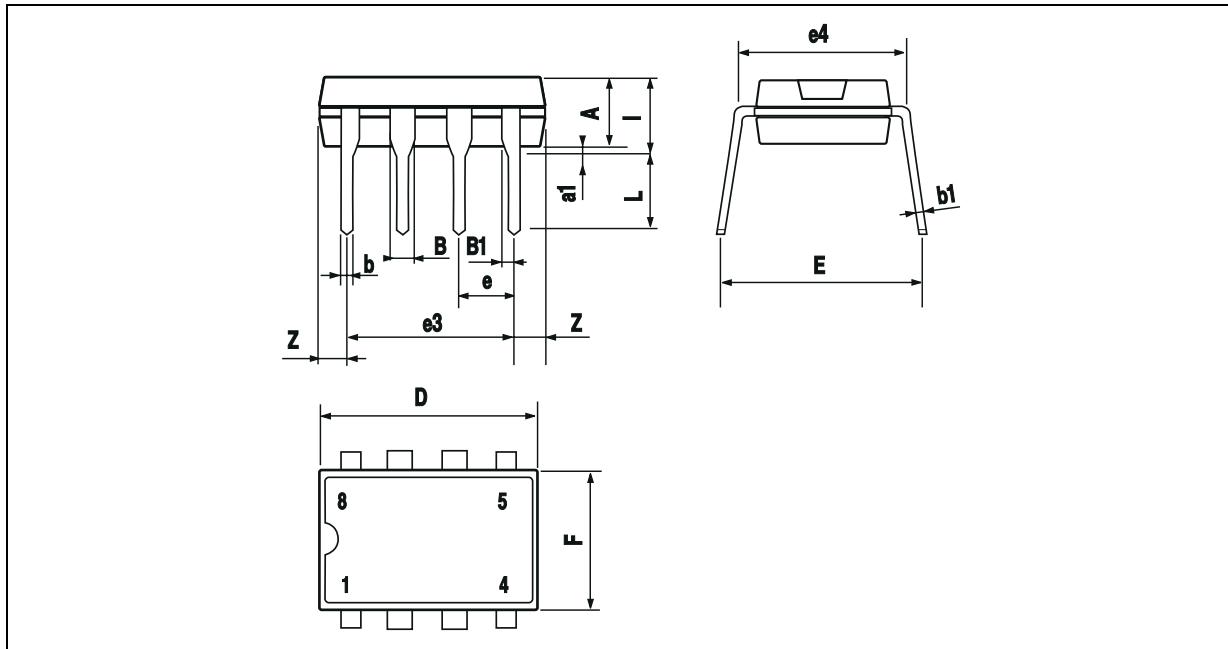


**THD + NOISE vs FREQUENCY**



**VOLTAGE GAIN AND PHASE vs FREQUENCY****THD + NOISE vs Vout**

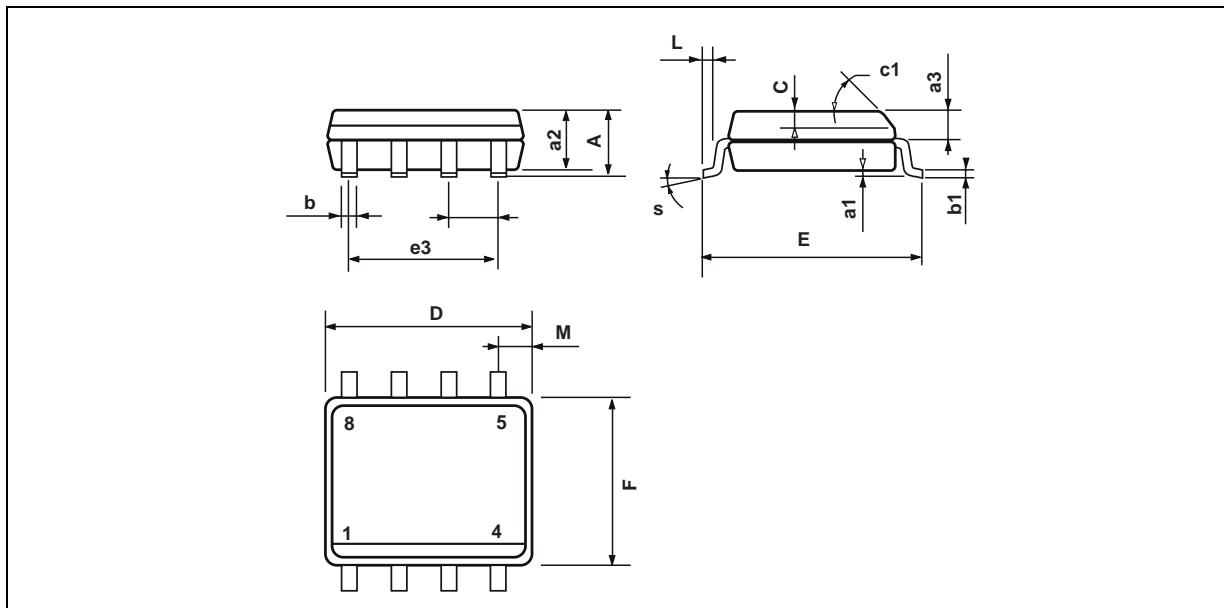
**PACKAGE MECHANICAL DATA**  
8 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

## **PACKAGE MECHANICAL DATA**

### **8 PINS - PLASTIC MICROPACKAGE (SO)**



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1			45° (typ.)			
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S			8° (max.)			

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